## NSN 5961-01-107-9560

Thyristor Semiconductor Device - Page 1 of 1



| View Online at https://aerobasegroup.com/nsn/5961-01-107-9560  |
|--|
| Inclosure Material:  |
| Plastic  |
| Overall Length:  |
| 0.363 inches   |
| Overall Width:   |
| 0.408 inches   |
| Mounting Facility Quantity:  |
| 1  |
| Mounting Method:   |
| Unthreaded hole  |
| Semiconductor Material:  |
| Silicon  |
| Voltage Rating In Volts Per Characteristic:  |
| 75.0 nonrepetitive peak reverse voltage and 50.0 repetitive peak reverse voltage   |
| Current Rating Per Characteristic:   |
| 2.50 amperes drain current universal and 4.00 amperes drain current horsepower metric and 2.75 amperes drain current nanoamperes |
| Power Rating Per Characteristic:   |
| 0.5 watts small-signal input power, common-collector blank   |
| Maximum Operating Tempurature Per Measurement Point:   |
| 150.0 degrees celsius ambient air  |
| Special Features:  |
| One insulator and one washer included  |
| Terminal Type And Quantity:  |
| 3 tab, solder lug  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
| <del></del>  |
| Demilitarization:  |
| No   |
| Fiig:  |
| A110a0   |
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